NPN Triple Diffused Planar Silicon Darlington Transistor



2SC4119

800V/15A Driver Applications

Applications

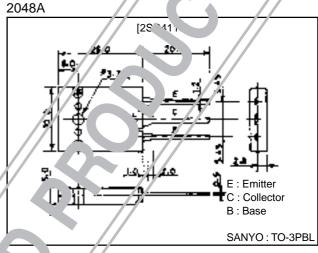
- \cdot Induction cookers.
- · High-voltage, high-power switching.

Features

- · High speed (adoption of MBIT process).
- · High breakdown voltage (V_{CBO} =1500V).
- · On-chip damper diode.
- · High reliability.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBC		1500	V
Collector-to-Emitter Votlage	VCI=0		800	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		15	А
Collector Current (Pulse)	ICF		30	Α
Base Current			3	А
Collector Dissipation		11	3.5	W
	1c=25°C		250	W
Junction Temperature	Tj		150	°C
Storage Temperature	-rtg		-55 to +150	°C

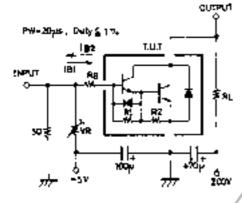
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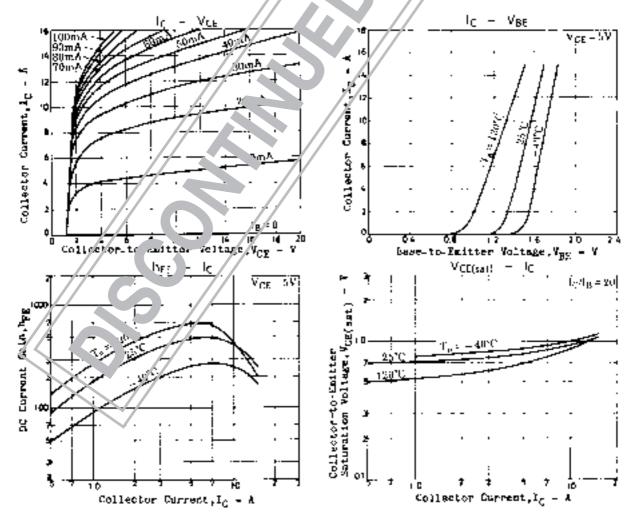
Electrical Characteristics at $Ta = 25^{\circ}C$

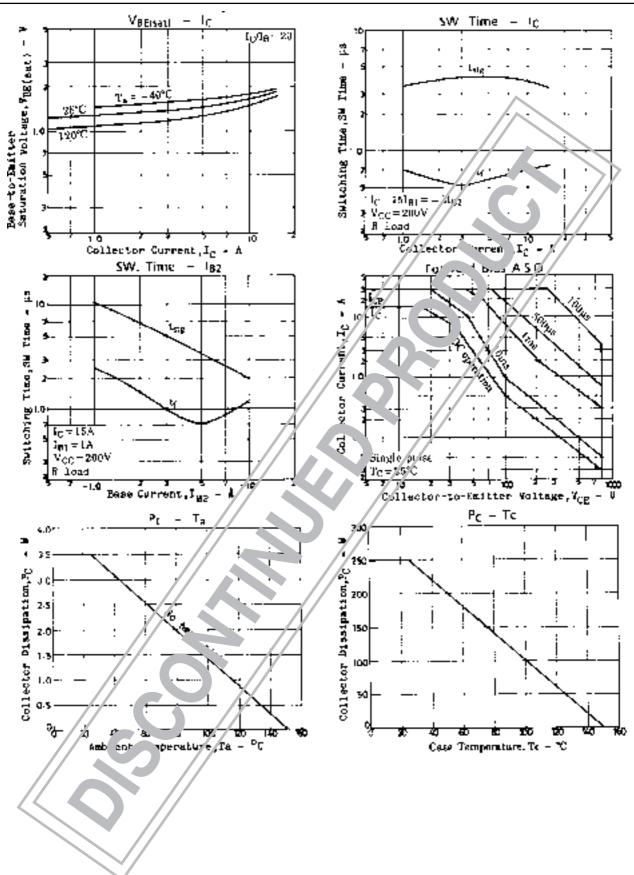
Parameter	Symbol	Conditions	Ratings			Unit
		Conditions		typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =800V, I _E =0			0.1	mA
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			600	mA
DC Current Gain	hFE	V _{CE} =5V, I _C =15A	25			
Collector Sustain Voltage	V _{CEO(sus)}	I _C =100mA, I _B =0	800			V
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =15A, I _B =0.75A			3.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =15A, I _B =0.75A			2.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =5mA, I _E =0	1 ,0			V
Diode Forward Voltage	VF	I _{EC} =15A			2 J	V
Fall Time	t _f	I_{C} =15A, I_{B1} =1A, I_{B2} =-5A, V_{CC} =200V, R_{L} =73.3 Ω			2.5	μs

Switching Time Test Circuit



Unit (resistance : V, capacitance : F)





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